







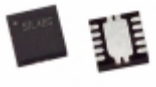
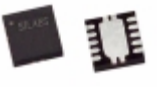


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|  | <h2>SI3460DV-T1-E3</h2> |
| | <p>Hersteller-Teilenummer: SI3460DV-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 20V 5.1A 6TSOP</p> <p>Datenblätter:  SI3460DV-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 236971 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|---|---|
| Teilenummer | SI3460DV-T1-E3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET N-CH 20V 5.1A 6TSOP |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 236971 pcs Stock |
| Serie | TrenchFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | SOT-23-6 Thin, TSOT-23-6 |
| Supplier Device-Gehäuse | 6-TSOP |
| Verlustleistung (max) | 1.1W (Ta) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 20V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 5.1A (Ta) |
| Rds On (Max) @ Id, Vgs | 27 mOhm @ 5.1A, 4.5V |
| VGS (th) (Max) @ Id | 450mV @ 1mA (Min) |
| Gate Charge (Qg) (Max) @ Vgs | 20nC @ 4.5V |
| Eingabekapazität (Ciss) (Max) @ Vds | - |
| Antriebsspannung (Max Rds On, Min Rds On) | 1.8V, 4.5V |
| Vgs (Max) | ±8V |
| Verpackung | Tape & Reel (TR) |



















































SI3460DV-T1-E3 ist neu im Original, Suche SI3460DV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3460DV-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3460DV-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|--|--|---|
|  <p>SI3460DDV-T1-GE3 Vishay / Siliconix MOSFET N-CH 20V 7.9A 6-TSOP</p> |  <p>SI3460DDV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 7.9A 6-TSOP</p> |  <p>SI3460DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 5.1A 6TSOP</p> |  <p>SI3460DV-T1-GE3 Vishay / Siliconix MOSFET N-CH 20V 5.1A 6TSOP</p> |
|  <p>SI3461-E02-GM Energy Micro (Silicon Labs) IC POWER MANAGEMENT CTLR 11VQFN</p> |  <p>SI3461-E01-GMR Energy Micro (Silicon Labs) IC POWER MANAGEMENT CTLR 11VQFN</p> |  <p>SI3460DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 5.1A 6TSOP</p> |  <p>SI3460DV VISHAY SI3460DV VISHAY</p> |

heiße Teile

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|  SI3458BDV-T1-GE3 |  SI3458BDV-T1-GE3 |  SI3458DV-T1-E3 |  SI3458DV-T1-E3 |  SI3458DV-T1-GE3 |
|  SI3459BDV-T1-E |  SI3459BDV-T1-E3 |  SI3459BDV-T1-E3 |  SI3459BDV-T1-GE3 |  SI3459BDV-T1-GE3 |
|  SI3459DV-T1-E3 |  SI3459DV-T1-E3 |  SI3459DV-T1-GE3 |  SI3460-E02-GMR |  SI3460-E03-GMR |
|  SI3460BDV-T1-E3 |  SI3460BDV-T1-E3 |  SI3460BDV-T1-GE3 |  SI3460BDV-T1-GE3 |  SI3460DDV |
|  SI3460DDV-T1-GE3 |  SI3460DDV-T1-GE3 |  SI3460DV |  SI3460DV-T1 |  SI3460DV-T1-E3 |
|  SI3460DV-T1-GE3 |  SI3460DV-T1-GE3 |  SI3461DV-T1-E3 |  SI3461DVT1-GE3 |  SI3464DV |
|  SI3464DV-T1-GE3 |  SI3464DV-T1-GE3 |  SI3465DV-T1-E3 |  SI3465DV-T1-E3 |  SI3465DV-T1-GE3 |
|  SI3465DV-T1-GE3 |  SI3467DV |  SI3467DV-T1-E3 |  SI3467DV-T1-E3 |  SI3467DV-T1-GE3 |
|  SI3467DV-T1-GE3 |  SI3469DV-T1 |  SI3469DV-T1-E3 |  SI3469DV-T1-E3 |  SI3469DV-T1-GE3 |
|  SI3469DV-T1-GE3 |  SI3471DV-T1-E3 |  SI3473CDV-T1-E3 |  SI3473CDV-T1-E3 |  SI3473CDV-T1-GE3 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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